

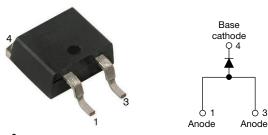
Vishay Semiconductors

RoHS

COMPLIANT HALOGEN

FREE

High Voltage Surface-Mount Input Rectifier Diode, 25 A



www.vishay.com

D²PAK 2L (TO-263AB 2L)

LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I _{F(AV)}	25 A				
V_R	1200 V				
V _F at I _F	1.14 V				
I _{FSM}	255 A				
T _J max.	175 °C				
Package	D ² PAK 2L (TO-263AB 2L)				
Circuit configuration	Single				

FEATURES

- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- 175 °C maximum operating junction temperature
- · Glass passivated pellet chip junction
- AEC-Q101 qualified
- Meets JESD 201 class 2 whisker test
- Flexible solution for reliable AC power rectification
- High surge, low V_F rugged blocking diode for DC charging stations
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- · Input rectification
- · On-board and off-board EV / HEV battery chargers

DESCRIPTION

The VS-25ETS12SLHM3 rectifier High Voltage Series has been optimized for very low forward voltage drop, with moderate leakage.

MECHANICAL DATA

Case: D²PAK 2L (TO-263AB 2L)

Molding compound meets UL 94 V-0 flammability rating **Terminals:** matte tin plated leads, solderable per

J-STD-002

OUTPUT CURRENT IN TYPICAL APPLICATIONS						
APPLICATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS						
Capacitive input filter T _A = 55 °C, T _J = 125 °C common heatsink of 1 °C/W	20	23	А			

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Sinusoidal waveform	25	A			
V _{RRM}		1200	V			
I _{FSM}		255	A			
V _F	10 A, T _J = 25 °C	1.0	V			
T _J		-40 to +175	°C			

VOLTAGE RATINGS						
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 175 °C mA			
VS-25ETS12S2LHM3	1200	1300	3			



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ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum average forward current	I _{F(AV)}	T _C = 125 °C, 180° conduction half sine wave	25				
Maximum peak one cycle	I _{FSM}	10 ms sine pulse, rated V _{RRM} applied, at T _J = 175 °C 215		Α			
non-repetitive surge current		10 ms sine pulse, no voltage reapplied, at $T_J = 175$ °C	255				
Maximum 12t far fraing	I ² t	10 ms sine pulse, rated V _{RRM} applied, at T _J = 175 °C	231	A ² s			
Maximum I ² t for fusing	1-1	10 ms sine pulse, no voltage reapplied, at T _J = 175 °C	326	A-S			
Maximum I ² √t for fusing	I ² √t	$t = 0.1$ ms to 10 ms, no voltage reapplied, at $T_J = 175$ °C	3260	A ² √s			

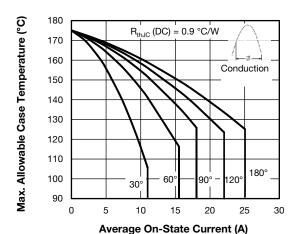
ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST (CONDITIONS	VALUES	UNITS	
Maximum forward voltage drop	V_{FM}	25 A, T _J = 25 °C		1.14	V	
Forward slope resistance	r _t	T 175 90		12	mΩ	
Threshold voltage	V _{F(TO)}	T _J = 175 °C		0.83	V	
		T _J = 25 °C		0.1		
Maximum reverse leakage current	I _{RM}	T _J = 150 °C	V_R = rated V_{RRM}	1.0	mA	
		T _J = 175 °C		3.0		

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range	T _J , T _{Stg}		-40 to +175	°C		
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	0.9			
Maximum thermal resistance, junction to ambient	R _{thJA} (1)	For D ² PAK version	62	°C/W		
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, and greased	0.5			
Approximate weight			2	g		
Approximate weight			0.07	OZ.		
Marking device		Case style: D ² PAK 2L (TO-263AB 2L)	25ETS	12SH		

Note

 $^{^{(1)}}$ When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 μ m) copper 40 °C/W

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Fig. 1 - Current Rating Characteristics

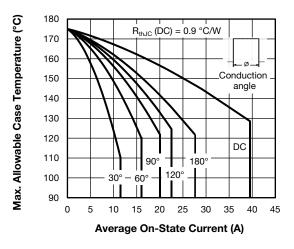


Fig. 2 - Current Rating Characteristics

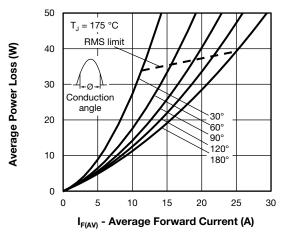


Fig. 3 - Forward Power Loss Characteristics

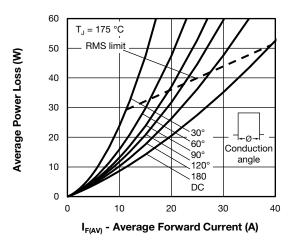


Fig. 4 - Forward Power Loss Characteristics

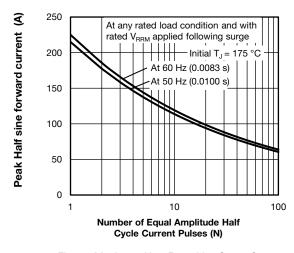


Fig. 5 - Maximum Non-Repetitive Surge Current

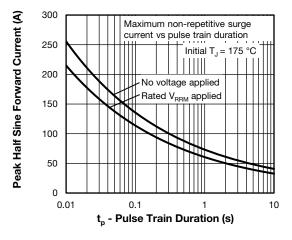


Fig. 6 - Maximum Non-Repetitive Surge Current

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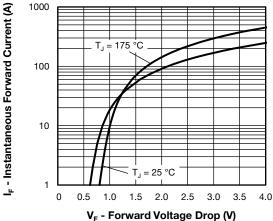


Fig. 7 - Forward Voltage Drop Characteristics

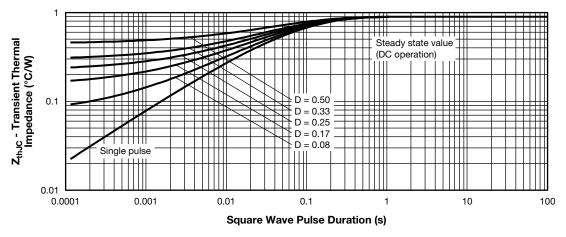


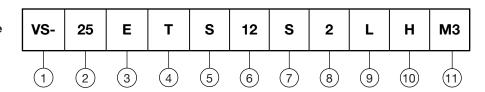
Fig. 8 - Thermal Impedance Z_{thJC} Characteristics



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ORDERING INFORMATION TABLE

Device code



- 1 Vishay Semiconductors product
- Current rating (25 = 25 A)
- Circuit configuration
 - E = single diode
- 4 Package:
 - $T = D^2PAK$
- 5 Type of silicon:
 - S = standard recovery rectifier
- 6 Voltage code x 100 = V_{RRM} 12 = 1200 V
- 7 S = surface mountable
- 2 = true 2 pin D²PAK
- L = tape and reel (left oriented), for different orientation, contact factory
- H = AEC-Q101 qualified
- Environmental digit:

M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-25ETS12S2LHM3	800	800	13" diameter reel		

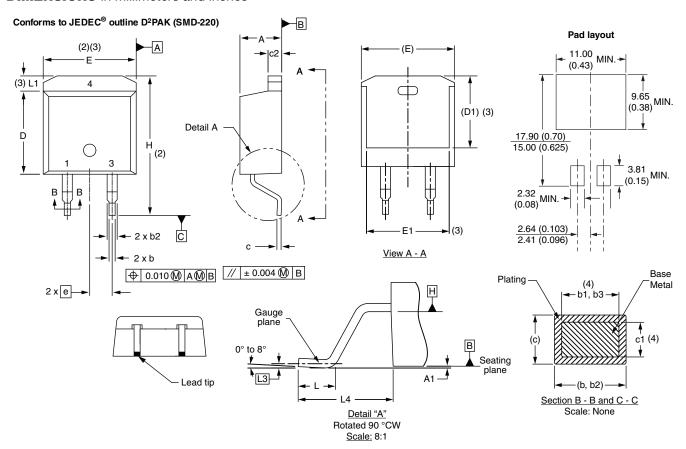
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?96683			
Part marking information	www.vishay.com/doc?96693			
Packaging information	www.vishay.com/doc?95032			



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D²PAK 2L (TO-263AB 2L)

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	IETERS	INCHES		NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIM	MILLIMETERS		INCHES	
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



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